

## P-Channel Enhancement Mode Power MOSFET

### Description

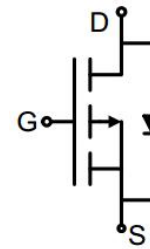
The G120P06M uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge. It can be used in a wide variety of applications.

### General Features

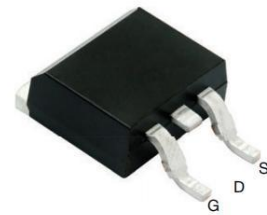
- $V_{DS}$  -60V
- $I_D$  (at  $V_{GS} = -10V$ ) -120A
- $R_{DS(ON)}$  (at  $V_{GS} = -10V$ ) < 8.5m $\Omega$
- 100% Avalanche Tested
- RoHS Compliant

### Application

- Power switch
- DC/DC converters



Schematic diagram



TO-263

### Ordering Information

Device	Package	Marking	Packaging
G120P06M	TO-263	G120P06	800pcs/Reel

### Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ , unless otherwise noted

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	-60	V
Continuous Drain Current	$I_D$	-120	A
Pulsed Drain Current (note1)	$I_{DM}$	-480	A
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Power Dissipation	$P_D$	277	W
Single pulse avalanche energy (note2)	$E_{AS}$	650	mJ
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 To 150	$^\circ\text{C}$

### Thermal Resistance

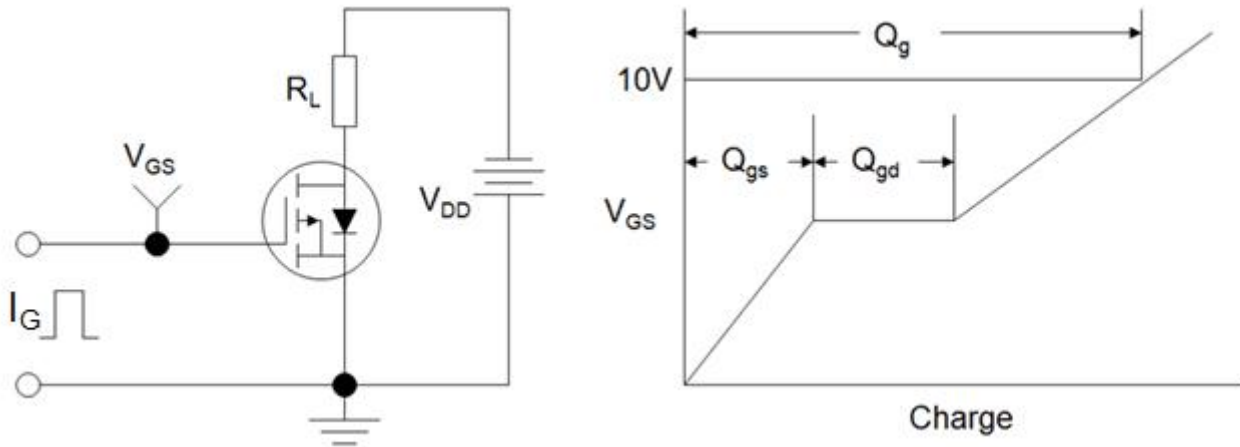
Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Ambient	$R_{thJA}$	65	$^\circ\text{C/W}$
Maximum Junction-to-Case	$R_{thJC}$	0.45	$^\circ\text{C/W}$

Specifications $T_J = 25^\circ\text{C}$ , unless otherwise noted						
Parameter	Symbol	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
<b>Static Parameters</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-60	--	--	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -60V, V_{GS} = 0V$	--	--	-1	$\mu A$
Gate-Source Leakage	$I_{GSS}$	$V_{GS} = \pm 20V$	--	--	$\pm 100$	nA
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1	-2.5	-3	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -20A$	--	7	8.5	m $\Omega$
Forward Transconductance	$g_{FS}$	$V_{DS} = -5V, I_D = -20A$	--	32	--	S
<b>Dynamic Parameters</b>						
Input Capacitance	$C_{iss}$	$V_{GS} = 0V,$ $V_{DS} = -30V,$ $f = 1.0\text{MHz}$	--	12215	--	pF
Output Capacitance	$C_{oss}$		--	946	--	
Reverse Transfer Capacitance	$C_{rss}$		--	673	--	
Total Gate Charge	$Q_g$	$V_{DD} = -30V,$ $I_D = -60A,$ $V_{GS} = -10V$	--	230	--	nC
Gate-Source Charge	$Q_{gs}$		--	50	--	
Gate-Drain Charge	$Q_{gd}$		--	35	--	
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = -30V,$ $I_D = -60A,$ $R_G = 1\Omega$	--	20	--	ns
Turn-on Rise Time	$t_r$		--	25	--	
Turn-off Delay Time	$t_{d(off)}$		--	110	--	
Turn-off Fall Time	$t_f$		--	50	--	
<b>Drain-Source Body Diode Characteristics</b>						
Continuous Body Diode Current	$I_S$	$T_C = 25^\circ\text{C}$	--	--	-120	A
Body Diode Voltage	$V_{SD}$	$T_J = 25^\circ\text{C}, I_{SD} = -20A, V_{GS} = 0V$	--	--	-1.2	V
Reverse Recovery Charge	$Q_{rr}$	$I_F = -30A, V_{GS} = 0V$ $di/dt = -100A/\mu s$	--	0.21	--	nC
Reverse Recovery Time	$T_{rr}$		--	91	--	ns

### Notes

1. Repetitive Rating: Pulse width limited by maximum junction temperature
2. Identical low side and high side switch with identical  $R_G$
3. EAS condition :  $T_J = 25^\circ\text{C}, V_{DD} = -50V, V_{GS} = -10V, L = 0.5\text{mH}, R_g = 25\Omega$

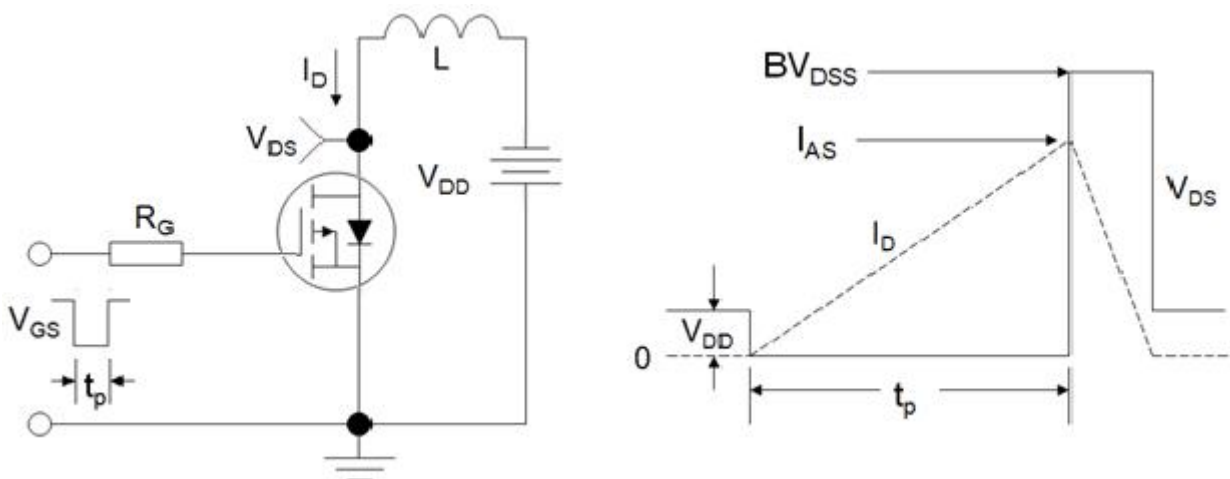
### Gate Charge Test Circuit



### Switch Time Test Circuit

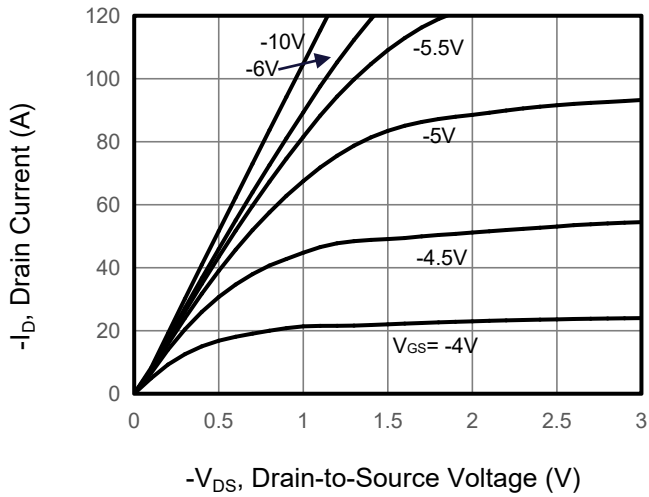


### EAS Test Circuit

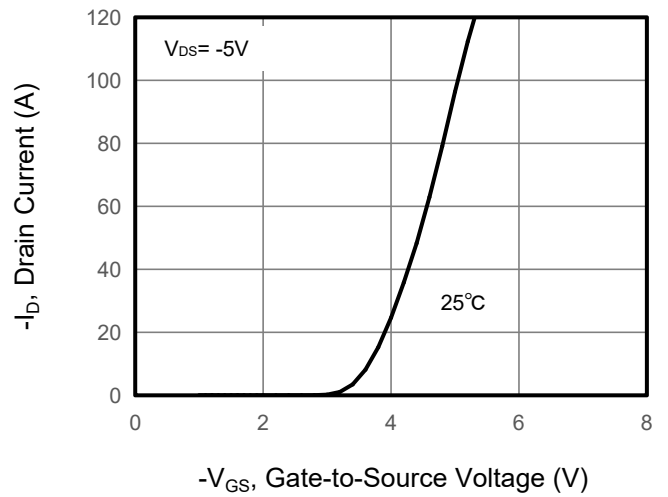


Typical Characteristics  $T_J = 25^\circ\text{C}$ , unless otherwise noted

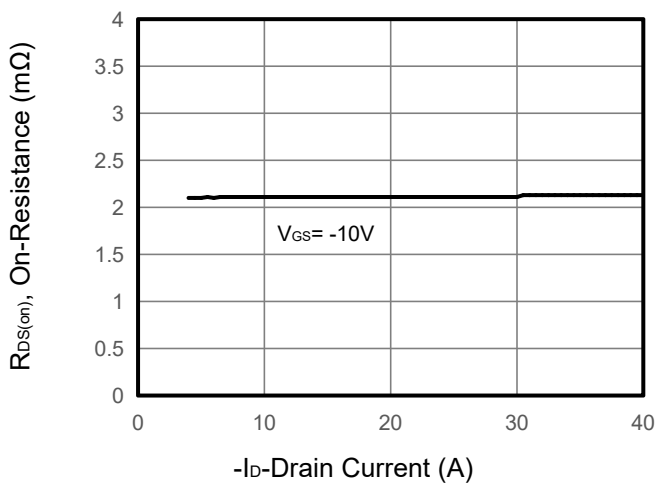
**Figure 1. Output Characteristics**



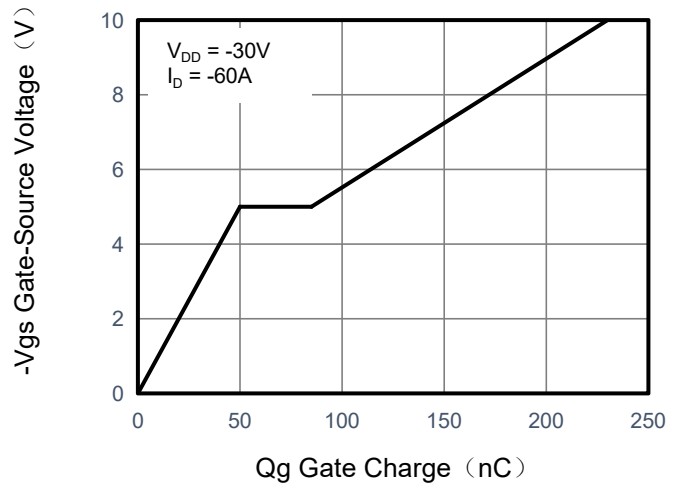
**Figure 2. Transfer Characteristics**



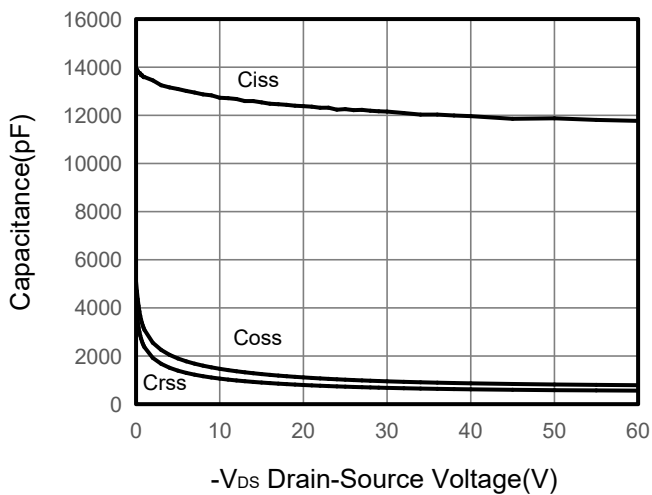
**Figure 3. Drain Source On Resistance**



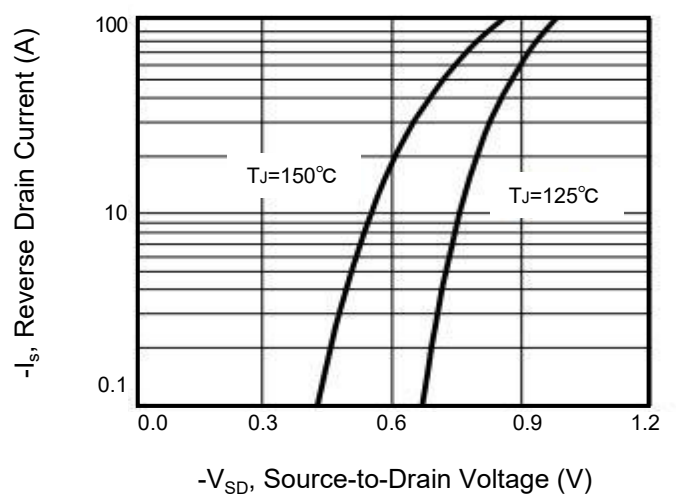
**Figure 4. Gate Charge**



**Figure 5. Capacitance**



**Figure 6. Source-Drain Diode Forward**



## Typical Characteristics $T_J = 25^\circ\text{C}$ , unless otherwise noted

Figure 7. Drain-Source On-Resistance

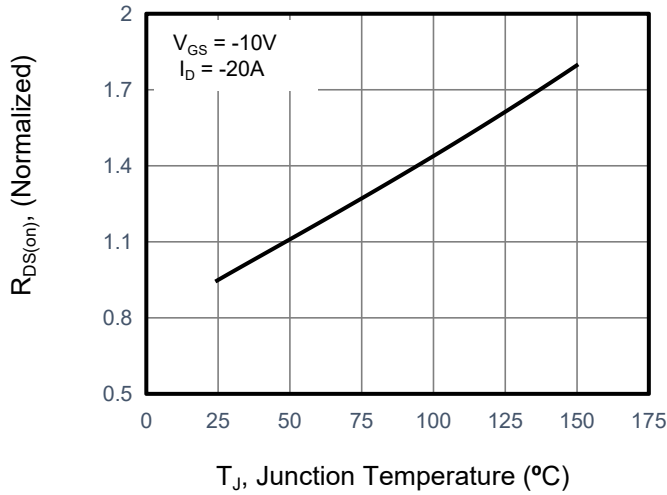


Figure 10. Safe Operation Area

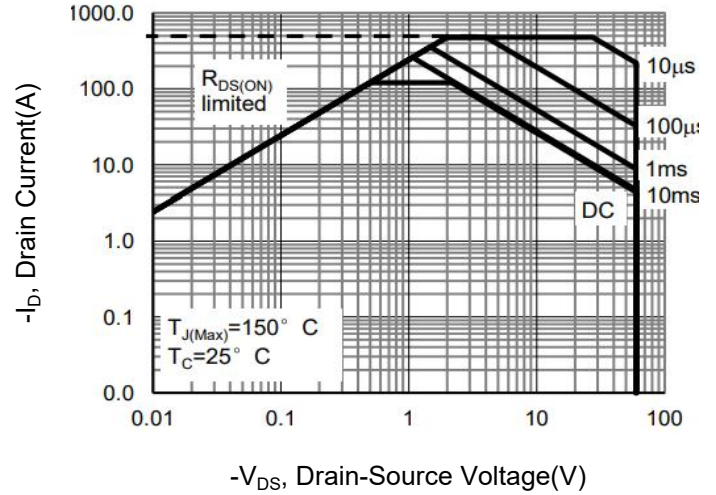
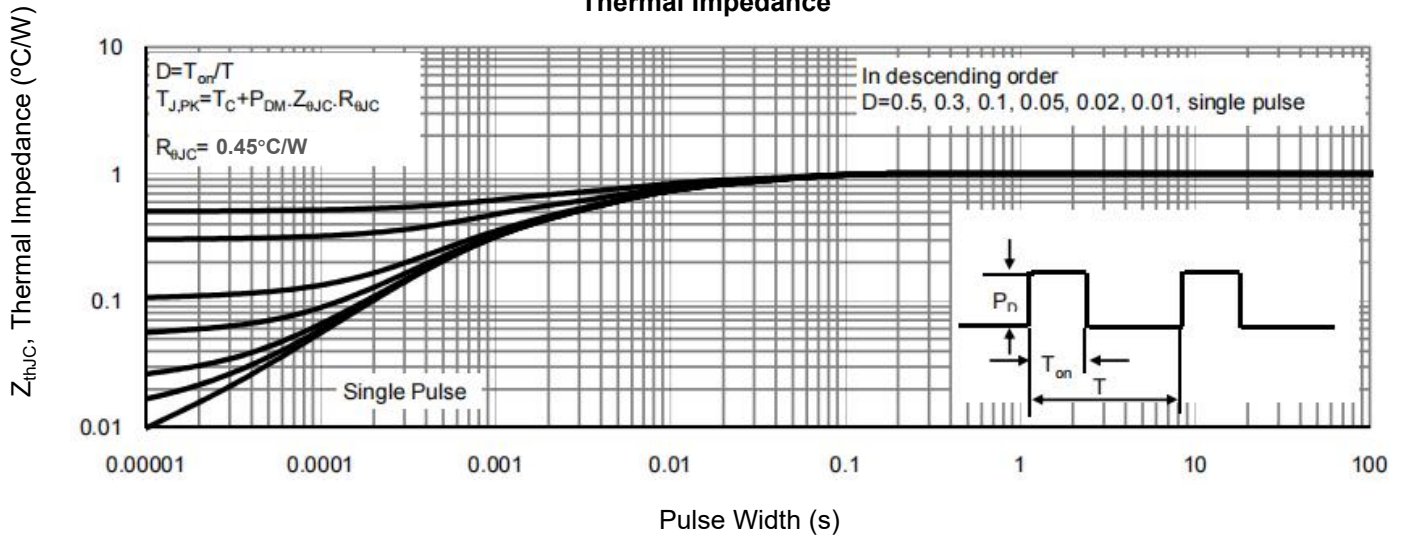
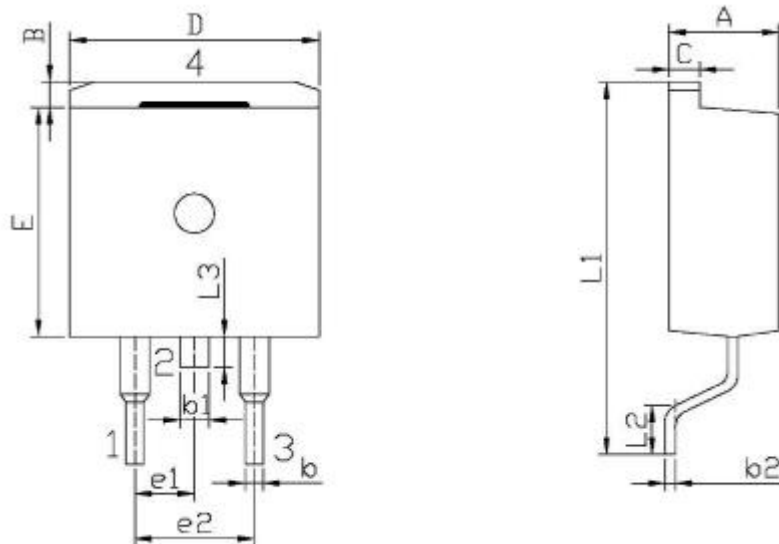


Figure 9. Normalized Maximum Transient Thermal Impedance



## TO-263 Package Mechanical Data



UNIT:mm

	MIN	MAX
A	4.30	4.70
B	1.00	1.40
b	0.70	0.90
b1	1.15	1.35
b2	0.40	0.60
C	1.20	1.40
D	9.80	10.20
E	9.00	9.40
e1	2.34	2.74
e2	4.88	5.28
L1	15.00	16.00
L2	2.24	2.84
L3	1.20	1.60